

Threshold Gain Calculations for Vertical-Cavity Surface-Emitting Lasers (VCSELs)

In a vertical-cavity surface-emitting laser (VCSEL) the emission of light occurs in the normal direction to the layer structure. This is contrary to the emission characteristics of the more common edge-emitting laser, where the light propagation is parallel to the layers and emission occurs through cleaved facets.

The different growth and emission characteristics of VCSELs, compared to edge-emitting lasers, give advantages when it comes to testing the samples during the fabrication steps. Tens of thousands of VCSELs can also be processed in parallel on a wafer.

The structure (see Figure 1) consists of a top and a bottom distributed Bragg reflector (DBR) structure with alternating high and low refractive index layers. Each layer in those DBR stacks is a quarter of a material wavelength thick.

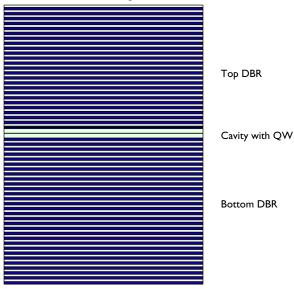


Figure 1: The structure of a vertical-cavity surface-emitting laser (VCSEL). The top and bottom distributed Bragg reflectors (DBRs) consists of alternating layers of GaAs (dark color) and AlGaAs (light color). The central cavity has one quantum well (QW) and one layer with an aluminum oxide annular ring.

The active material, providing the gain, is located in the cavity between the DBRs. It usually consists of one or more quantum well (QW) layers. A quantum well layer is a thin layer of a thickness of 100 Å or less. The band gap energy of the quantum well layers is smaller than the band gap energy of the adjacent layers. This forms a very narrow potential well, with a set of discrete energy levels. Since the energy levels depend both on the

material compositions and the quantum well layer thickness, the emission wavelength can easily be changed by slightly changing the layer thicknesses and/or the material compositions.

As the quantum wells are so thin, the gain is very small. Thus, the DBRs must have a very high reflectivity — often larger than 99%. Otherwise, the gain cannot balance the mirror losses.

VCSELs are used in many applications, such as for computer mice, laser printers, and in communication.

In this model, an eigenfrequency study is used to find the resonance frequency and threshold gain for an oxide-confined, GaAs-based, vertical-cavity surface-emitting laser (VCSEL). The oxide can provide both electrical and optical confinement, but only the optical properties are studied in this model. Moreover, the model is extended to calculate the far-field by using a closed surface surrounding the VCSEL.

Model Definition

The model is set up in 2D axisymmetry for the structure in Figure 1. The modes searched for have an azimuthal dependence of $\exp(-j\varphi)$, where φ is the angle of rotation around the symmetry axis. Modes with this type of azimuthal dependence can be linearly and circularly polarized and have nonzero intensity on the symmetry axis.

The simulations are performed in two steps. A regular eigenfrequency analysis is first performed, to find good initial values for the subsequent nonlinear eigenfrequency analysis.

The resonance frequencies and threshold gain compare well to values presented in Ref. 1. This paper collects the results from different computational methods on this benchmark problem.

Figure 2 shows the mode field after the initial Eigenfrequency study. The mode is confined essentially between the top and the bottom DBRs.

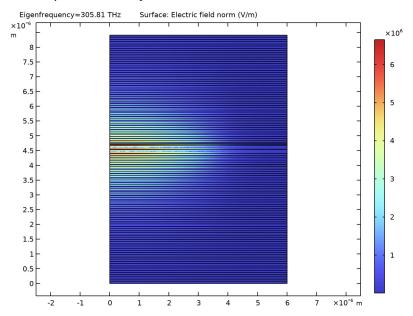


Figure 2: Surface plot of the mode field after the initial Eigenfrequency study. The plot shows the norm of the electric field, with the symmetry axis at r = 0.

The result after the second (nonlinear) eigenfrequency study is shown in Figure 3. Here a height distribution feature was used to make the field distribution a bit clearer. However, the field distribution is very similar to the distribution after the first study.

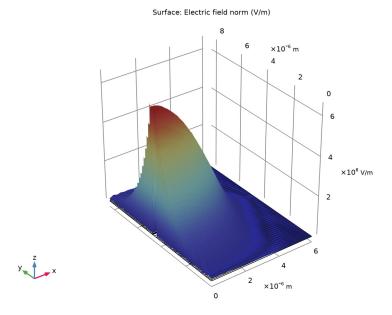


Figure 3: The mode field distribution after the second study.

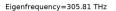
The resonance wavelength and the threshold gain coefficient are summarized in Table 1 below. The results agree well with Figures 2 and 3 in Ref. 1 for oxide position 3.

TABLE I: RESONANCE WAVELENGTH AND THRESHOLD GAIN FOR OXIDE POSITION 3.

Resonance wavelength	Threshold gain
980.3 nm	1217 cm ⁻¹

In addition, a far-field calculation is performed using an air domain enclosing the VSCEL. The resonance wavelength and threshold gain are in well agreement with Ref. 1 and Table 1.

The far-field radiation pattern at the eigenfrequency 305.8 THz is shown in Figure 4 indicating that the radiation is slightly stronger in the top direction.





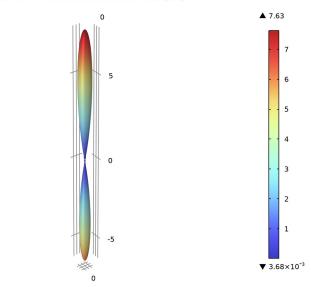


Figure 4: 3-D far-field radiation pattern.

Reference

1. P. Bienstman and others, "Comparison of optical VCSEL models on the simulation of oxide-confined devices," IEEE J. Quantum Electron., vol. 37, no. 12, pp. 1618-1631, 2001.

Application Library path: Wave_Optics_Module/Verification_Examples/ vertical_cavity_surface_emitting_laser

Modeling Instructions

From the File menu, choose New.

NEW

In the New window, click Model Wizard.

MODEL WIZARD

- I In the Model Wizard window, click 2D Axisymmetric.
- 2 In the Select Physics tree, select Optics>Wave Optics>Electromagnetic Waves, Frequency Domain (ewfd).
- 3 Click Add.
- 4 Click Add.
- 5 Click Study.
- 6 In the Select Study tree, select General Studies>Eigenfrequency.
- 7 Click **Done**.

GEOMETRY I

The model geometry is available as a parameterized geometry sequence in a separate MPH-file. If you want to build it from scratch, follow the instructions in Appendix: Geometry Modeling Instructions. Otherwise load it from file with the following steps.

- I In the Geometry toolbar, click Insert Sequence and choose Insert Sequence.
- 2 Browse to the model's Application Libraries folder and double-click the file vertical_cavity_surface_emitting_laser_geom_sequence.mph.
- **3** In the **Insert Sequence** dialog box, click **OK**.
- 4 In the Geometry toolbar, click **Build All**.
- 5 Click the **Zoom Extents** button in the **Graphics** toolbar.

6 In the Model Builder window, under Component I (compl) click Geometry I.

GLOBAL DEFINITIONS

The parameters for the geometry was included in the loaded geometry sequence file.

Geometry Parameters

- I In the Model Builder window, under Global Definitions click Parameters I.
- 2 In the Settings window for Parameters, type Geometry Parameters in the Label text field.

General Parameters

Now, add some general parameters, like the intended wavelength, and some parameters defining the materials.

- I In the Home toolbar, click Pi Parameters and choose Add>Parameters.
- 2 In the **Settings** window for **Parameters**, type General Parameters in the **Label** text field.
- 3 Locate the Parameters section. Click **Load from File**.
- **4** Browse to the model's Application Libraries folder and double-click the file vertical_cavity_surface_emitting_laser_general_parameters.txt.

Material Parameters

I In the Home toolbar, click P Parameters and choose Add>Parameters.

- 2 In the Settings window for Parameters, type Material Parameters in the Label text field.
- 3 Locate the Parameters section. Click **Load from File.**
- **4** Browse to the model's Application Libraries folder and double-click the file vertical_cavity_surface_emitting_laser_material_parameters.txt.

ELECTROMAGNETIC WAVES, FREQUENCY DOMAIN (EWFD)

The geometry is cylindrically symmetric. Solve for modes having an $\exp(-j\varphi)$ dependence, where φ is the rotation angle around the symmetry axis. With this rotation angle variation, the modes can be nonzero on the symmetry axis.

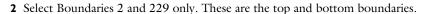
- I In the Model Builder window, under Component I (comp I) click Electromagnetic Waves, Frequency Domain (ewfd).
- 2 In the Settings window for Electromagnetic Waves, Frequency Domain, locate the Out-of-Plane Wave Number section.
- **3** In the *m* text field, type 1. This will give you the expected rotation angle variation, discussed above.

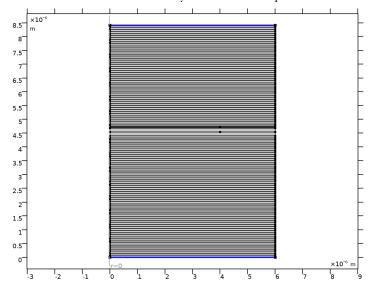
Scattering Boundary Condition I

- I In the Physics toolbar, click Boundaries and choose Scattering Boundary Condition.
- 2 Click the Select Box button in the Graphics toolbar.
- 3 Select Boundaries 236–349 only. These entities constitute the outer boundary of the rotationally symmetric cylinder.
- 4 In the Settings window for Scattering Boundary Condition, locate the Scattering Boundary Condition section.
- 5 From the Scattered wave type list, choose Cylindrical wave.

Imbedance Boundary Condition I

In the Physics toolbar, click — Boundaries and choose Impedance Boundary Condition.





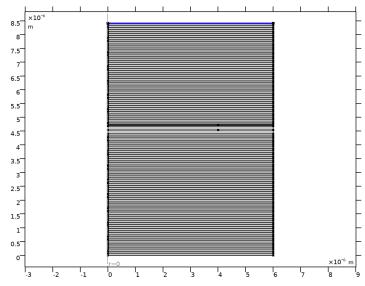
MATERIALS

Now, define all the materials for the structure. The selections that will be used was defined when the geometry was built. Please consult Appendix: Geometry Modeling Instructions for the details about defining cumulative selections when building the geometry sequence.

Air Superstrate

- I In the Model Builder window, under Component I (compl) right-click Materials and choose Blank Material.
- 2 In the Settings window for Material, type Air Superstrate in the Label text field.
- 3 Locate the Geometric Entity Selection section. From the Geometric entity level list, choose Boundary.

4 Select Boundary 229 only, which is the top boundary.



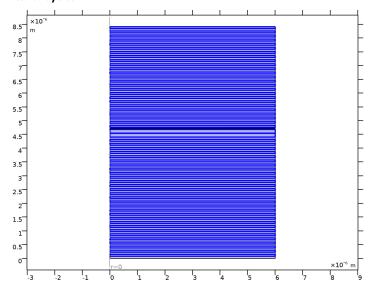
5 Locate the **Material Contents** section. In the table, enter the following settings:

Property	Variable	Value	Unit	Property group	
Refractive index, real part	n_iso ; nii = n_iso, nij = 0	n_air	I	Refractive index	
Refractive index, imaginary part	ki_iso ; kiii = ki_iso, kiij = 0	0	1	Refractive index	

GaAs

- I Right-click Materials and choose Blank Material.
- 2 In the Settings window for Material, type GaAs in the Label text field.

3 Locate the Geometric Entity Selection section. From the Selection list, choose GaAs Layers.



4 Locate the **Material Contents** section. In the table, enter the following settings:

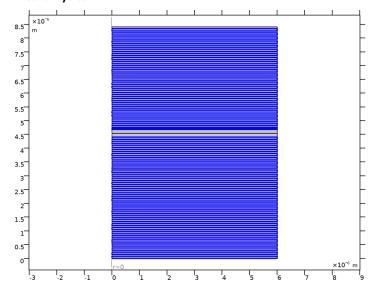
Property	Variable Valu		Unit	Property group	
Refractive index, real part	n_iso ; nii = n_iso, nij = 0	n_GaAs	I	Refractive index	
Refractive index, imaginary part	ki_iso; kiii = ki_iso, kiij = 0	0	I	Refractive index	

5 Right-click GaAs and choose Duplicate.

AlGaAs

- I In the Model Builder window, under Component I (compl)>Materials click GaAs I (mat3).
- 2 In the Settings window for Material, type AlGaAs in the Label text field.

3 Locate the Geometric Entity Selection section. From the Selection list, choose AlGaAs Layers.



4 Locate the **Material Contents** section. In the table, enter the following settings:

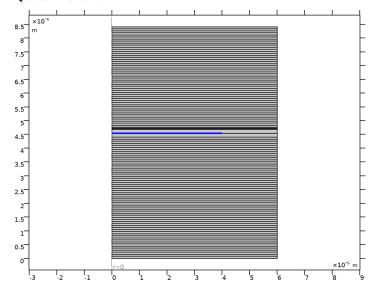
Property	Variable	Value	Unit	Property group
Refractive index, real part	n_iso ; nii = n_iso, nij = 0	n_AlGaAs	I	Refractive index
Refractive index, imaginary part	ki_iso ; kiii = ki_iso, kiij = 0	0	I	Refractive index

5 Right-click AlGaAs and choose Duplicate.

QW Gain

- I In the Model Builder window, under Component I (compl)>Materials click AlGaAs I (mat4).
- 2 In the Settings window for Material, type QW Gain in the Label text field.

3 Locate the Geometric Entity Selection section. From the Selection list, choose QW Gain Domain.



4 Locate the **Material Contents** section. In the table, enter the following settings:

Property	Variable	Value	Unit	Property group
Refractive index, real part	n_iso ; nii = n_iso, nij = 0	n_QW	I	Refractive index
Refractive index, imaginary part	ki_iso ; kiii = ki_iso, kiij = 0	kappa_QW	I	Refractive index

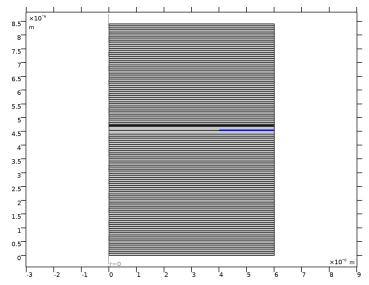
A variable named kappa_QW will be added after all materials have been defined.

5 Right-click QW Gain and choose Duplicate.

QW Loss

- I In the Model Builder window, under Component I (compl)>Materials click QW Gain I (mat5).
- 2 In the Settings window for Material, type QW Loss in the Label text field.

3 Locate the Geometric Entity Selection section. From the Selection list, choose QW Loss Domain.



4 Locate the **Material Contents** section. In the table, enter the following settings:

Property	Variable	Value	Unit	Property group
Refractive index, real part	n_iso ; nii = n_iso, nij = 0	n_QW	I	Refractive index
Refractive index, imaginary part	ki_iso ; kiii = ki_iso, kiij = 0	kappa_QW_lo	I	Refractive index

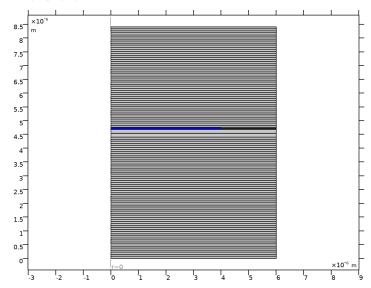
AlGaAs (mat3)

In the Model Builder window, right-click AlGaAs (mat3) and choose Duplicate.

AIAs

- I In the Model Builder window, under Component I (compl)>Materials click AlGaAs I (mat6).
- 2 In the Settings window for Material, type AlAs in the Label text field.

3 Locate the Geometric Entity Selection section. From the Selection list, choose AlAs Domain.



4 Locate the **Material Contents** section. In the table, enter the following settings:

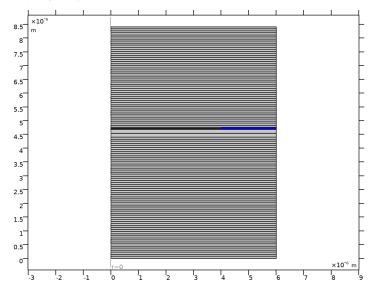
Property	Variable	Value	Unit	Property group
Refractive index, real part	n_iso ; nii = n_iso, nij = 0	n_AlAs	1	Refractive index
Refractive index, imaginary part	ki_iso; kiii = ki_iso, kiij = 0	0	I	Refractive index

5 Right-click AIAs and choose Duplicate.

AIOx

- I In the Model Builder window, under Component I (compl)>Materials click AIAs I (mat7).
- 2 In the Settings window for Material, type Alox in the Label text field.

3 Locate the Geometric Entity Selection section. From the Selection list, choose AlOx Domain.



4 Locate the Material Contents section. In the table, enter the following settings:

Property	Variable	Value	Unit	Property group
Refractive index, real part	n_iso ; nii = n_iso, nij = 0	n_A10x	I	Refractive index
Refractive index, imaginary part	ki_iso; kiii = ki_iso, kiij = 0	0	I	Refractive index

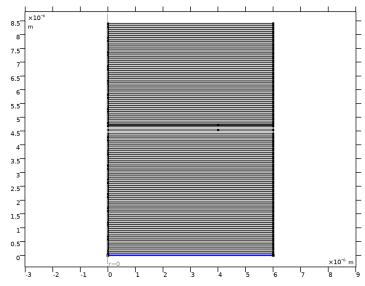
Air Superstrate (mat I)

In the Model Builder window, right-click Air Superstrate (mat1) and choose Duplicate.

GaAs Substrate

- I In the Model Builder window, under Component I (compl)>Materials click Air Superstrate I (mat8).
- 2 In the Settings window for Material, type GaAs Substrate in the Label text field.
- 3 Locate the Geometric Entity Selection section. Click Clear Selection.

4 Select Boundary 2 only, which is the bottom boundary.



5 Locate the **Material Contents** section. In the table, enter the following settings:

Property	Variable	Value	Unit	Property group	
Refractive index, real part	n_iso ; nii = n_iso, nij = 0	n_GaAs		Refractive index	
Refractive index, imaginary part	ki_iso ; kiii = ki_iso, kiij = 0	0	I	Refractive index	

DEFINITIONS

Define a variable for the quantum well gain coefficient. This variable will be used by the first physics interface and in the first study. In the second study and for the second physics interface, the quantum well gain coefficient will be self-consistently solved for.

Variables 1

- I In the Model Builder window, under Component I (compl) right-click Definitions and choose Variables.
- 2 In the Settings window for Variables, locate the Variables section.

3 In the table, enter the following settings:

Name	Expression	Unit	Description
kappa_QW	kappa_QW_gain		Refractive index, quantum well, gain domain, imaginary part

MESH I

Setting up the mesh sequence is again simplified by using the selections defined as part of the geometry sequence.

Free Triangular 1

In the Mesh toolbar, click Free Triangular.

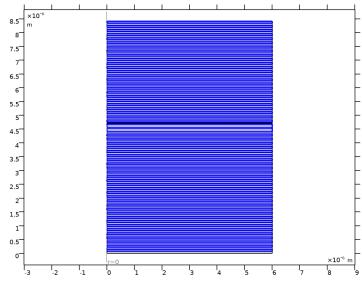
Size

- I In the Model Builder window, click Size.
- 2 In the Settings window for Size, locate the Element Size section.
- 3 From the Predefined list, choose Extra coarse.

GaAs

- I In the Model Builder window, right-click Mesh I and choose Size.
- 2 In the Settings window for Size, type GaAs in the Label text field.
- 3 Locate the Geometric Entity Selection section. From the Geometric entity level list, choose Domain.

4 From the Selection list, choose GaAs Layers.

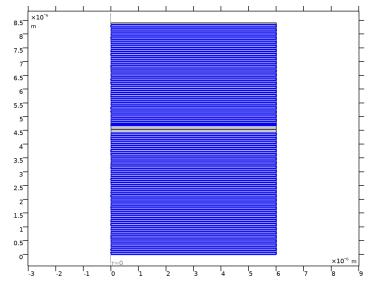


- 5 Locate the Element Size section. Click the Custom button.
- 6 Locate the Element Size Parameters section.
- 7 Select the Maximum element size check box. In the associated text field, type 1da0/6/ n_GaAs.
- 8 Right-click GaAs and choose Duplicate.

AlGaAs

- I In the Model Builder window, under Component I (compl)>Mesh I click GaAs I.
- 2 In the Settings window for Size, type AlGaAs in the Label text field.

3 Locate the Geometric Entity Selection section. From the Selection list, choose AlGaAs Layers.

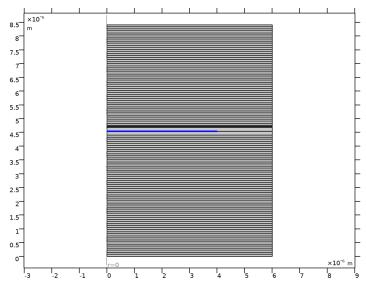


- 4 Locate the Element Size Parameters section. In the Maximum element size text field, type lda0/6/n_AlGaAs.
- 5 Right-click AlGaAs and choose Duplicate.

QW Gain

- I In the Model Builder window, under Component I (compl)>Mesh I click AlGaAs I.
- 2 In the Settings window for Size, type QW Gain in the Label text field.

3 Locate the Geometric Entity Selection section. From the Selection list, choose QW Gain Domain.

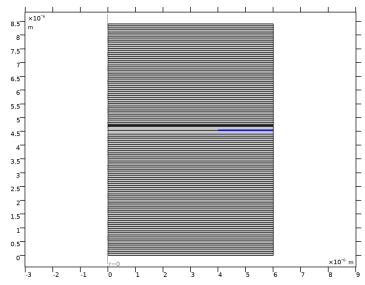


- 4 Locate the Element Size Parameters section. In the Maximum element size text field, type lda0/6/n_QW.
- 5 Right-click QW Gain and choose Duplicate.

QW Loss

- I In the Model Builder window, under Component I (comp I)>Mesh I click QW Gain I.
- 2 In the Settings window for Size, type QW Loss in the Label text field.

3 Locate the Geometric Entity Selection section. From the Selection list, choose QW Loss Domain.

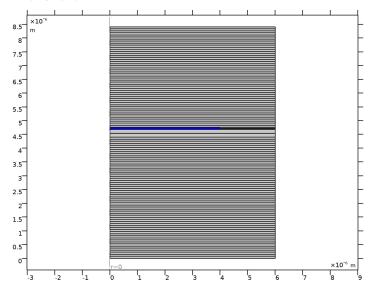


4 Right-click **QW Loss** and choose **Duplicate**.

AIAs

- I In the Model Builder window, under Component I (compl)>Mesh I click QW Loss I.
- 2 In the Settings window for Size, type AlAs in the Label text field.

3 Locate the Geometric Entity Selection section. From the Selection list, choose AlAs Domain.

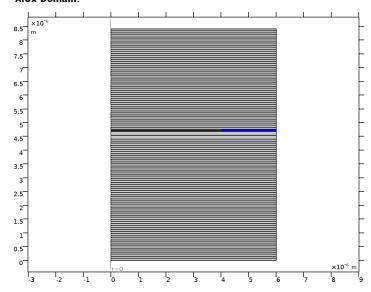


- 4 Locate the Element Size Parameters section. In the Maximum element size text field, type lda0/6/n_AlAs.
- 5 Right-click AIAs and choose Duplicate.

AIOx

- I In the Model Builder window, under Component I (compl)>Mesh I click AIAs I.
- 2 In the Settings window for Size, type Alox in the Label text field.

3 Locate the Geometric Entity Selection section. From the Selection list, choose AlOx Domain.



4 Locate the Element Size Parameters section. In the Maximum element size text field, type lda0/6/n_Al0x.

Free Triangular 1

- I In the Model Builder window, click Free Triangular I.
- 2 Drag and drop below AIOx.
- 3 In the Settings window for Free Triangular, click **Build All**.

STUDY I

Step 1: Eigenfrequency

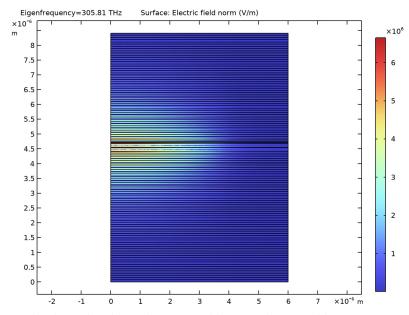
- I In the Model Builder window, under Study I click Step I: Eigenfrequency.
- 2 In the Settings window for Eigenfrequency, locate the Study Settings section.
- 3 Select the **Desired number of eigenfrequencies** check box. In the associated text field, type 1.
- 4 In the Search for eigenfrequencies around shift text field, type f0.
- 5 Locate the Physics and Variables Selection section. Select the $\label{eq:model_configuration} \mbox{Modify model configuration for study step } check \ box.$

- 6 In the tree, select Component I (compl)>Electromagnetic Waves, Frequency Domain 2 (ewfd2).
- 7 Click O Disable in Model. If you do not disable the second physics interface, it will not be possible to rerun this study once the second physics is fully defined as it will also define a variable called kappa_QW.
- 8 In the Home toolbar, click **Compute**.

RESULTS

Electric Field (ewfd)

I In the Electric Field (ewfd) toolbar, click **Plot**.



This shows that the mode is centered between the top and bottom DBRs and that the field has a nonzero amplitude on the symmetry axis.

Eigenfrequencies (ewfd)

- I In the Model Builder window, expand the Results>Derived Values node, then click Eigenfrequencies (ewfd).
- 2 In the Settings window for Global Evaluation, locate the Expressions section.

3 In the table, enter the following settings:

Expression	Unit	Description
ewfd.lambda0	nm	Wavelength in free space

The wavelength is added to the table in addition to the already existing variables for the frequency ewfd.freq and the quality factor ewfd.Qfactor.

4 Click **= Evaluate**.

The quality factor is a measure of the loss in the system. A higher quality factor, means less loss.

DEFINITIONS

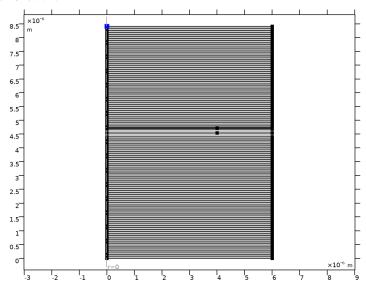
Now define the settings for the second physics interface and the second study.

Start by adding a point integration operator. This operator will be used when normalizing the field.

Point Evaluation

- I In the Definitions toolbar, click Nonlocal Couplings and choose Integration.
- 2 In the Settings window for Integration, type Point Evaluation in the Label text field.
- 3 Locate the Source Selection section. From the Geometric entity level list, choose Point.
- 4 Click Paste Selection.
- 5 In the Paste Selection dialog box, type 115 in the Selection text field. This corresponds to the point where the top boundary crosses the symmetry axis.

6 Click OK.



- 7 In the Settings window for Integration, locate the Advanced section.
- 8 From the Method list, choose Summation over nodes.

ELECTROMAGNETIC WAVES, FREQUENCY DOMAIN 2 (EWFD2)

- I In the Model Builder window, under Component I (compl) click Electromagnetic Waves, Frequency Domain 2 (ewfd2).
- 2 In the Settings window for Electromagnetic Waves, Frequency Domain, click to expand the **Equation** section.
- 3 From the Equation form list, choose Frequency domain.
- **4** From the **Frequency** list, choose **User defined**. In the f text field, type f req1. A dependent variable with this name will be added later.
- **5** Locate the **Out-of-Plane Wave Number** section. In the *m* text field, type 1.

Initial Values 1

When later solving for the frequency and the threshold gain, the field solution will be found close to the initial value specified below.

- I In the Model Builder window, under Component I (compl)>Electromagnetic Waves, Frequency Domain 2 (ewfd2) click Initial Values I.
- 2 In the Settings window for Initial Values, locate the Initial Values section.

3 Specify the **E**2 vector as

<pre>withsol('sol1',ewfd.Er)</pre>	r
<pre>withsol('sol1',ewfd.Ephi)</pre>	phi
<pre>withsol('sol1',ewfd.Ez)</pre>	z

The withsol operator evaluates the provided expression in the second argument, using the solution specified in the first argument.

ELECTROMAGNETIC WAVES, FREQUENCY DOMAIN (EWFD)

Impedance Boundary Condition I, Scattering Boundary Condition I

- I In the Model Builder window, under Component I (compl)>Electromagnetic Waves, Frequency Domain (ewfd), Ctrl-click to select Scattering Boundary Condition I and Impedance Boundary Condition 1.
- 2 Right-click and choose Copy.

ELECTROMAGNETIC WAVES, FREQUENCY DOMAIN 2 (EWFD2)

- I In the Model Builder window, under Component I (compl) right-click Electromagnetic Waves, Frequency Domain 2 (ewfd2) and choose Paste Multiple Items.
 - To be able to add Global Equations nodes, you must first enable Equation-Based **Contributions** from the **Show More Options** dialog.
- 2 Click the Show More Options button in the Model Builder toolbar.
- **3** In the **Show More Options** dialog box, in the tree, select the check box for the node Physics>Equation-Based Contributions.
- 4 In the tree, select the check box for the node Physics>Advanced Physics Options.
- 5 Click OK.

Now, you are ready to add Global Equations nodes.

Frequency

- I In the Physics toolbar, click A Global and choose Global Equations.
- 2 In the Settings window for Global Equations, type Frequency in the Label text field.

3 Locate the Global Equations section. In the table, enter the following settings:

Name	f(u,ut,utt,t) (l)	Initial value (u_0) (1)	Initial value (u_t0) (1/s)	Description
freq1	<pre>intop1(real(withso l('sol1', ewfd.Er)))- intop1(real(ewfd2. Er))</pre>	withsol('sol1', ewfd.freq)	0	Frequency

Here, the previously defined point integration operator is used to normalize the real part of a field value to a specified value in the point the operator was defined for. The withsol operator is again used for evaluating an expression from the first physics using a solution from the first study.

- 4 Click to expand the **Discretization** section. From the Value type when using splitting of complex variables list, choose Real, as the frequency is a real quantity.
- 5 Locate the Units section. Click Select Dependent Variable Quantity.
- 6 In the Physical Quantity dialog box, type frequency in the text field.
- 7 Click **Filter**.
- 8 In the tree, select General>Frequency (Hz).
- 9 Click OK.
- 10 In the Settings window for Global Equations, locate the Units section.
- II Click Select Source Term Quantity.
- 12 In the Physical Quantity dialog box, type electric in the text field.
- 13 Click **Filter**.
- 14 In the tree, select Electromagnetics>Electric field (V/m).
- I5 Click OK.
- 16 Right-click Frequency and choose Duplicate.

Gain

- I In the Model Builder window, under Component I (compl)>Electromagnetic Waves, Frequency Domain 2 (ewfd2) click Frequency I (ODE2).
- 2 In the Settings window for Global Equations, type Gain in the Label text field.

3 Locate the Global Equations section. In the table, enter the following settings:

Name	f(u,ut,utt,t) (V/m)	Initial value (u_0) (Hz)	Initial value (u_t0) (Hz/ s)	Description
kappa_QW	<pre>intop1(imag(withs ol('sol1', ewfd.Er)))- intop1(imag(ewfd2 .Er))</pre>	kappa_QW_ gain	0	Refractive index, QW, imaginary part

Here, the imaginary part of the field value in the point defined by the integration operator is set to a specified value.

- 4 Locate the Units section. Click Select Dependent Variable Quantity.
- 5 In the Physical Quantity dialog box, type dimension in the text field.
- 6 Click **Filter**.
- 7 In the tree, select General>Dimensionless (1).
- 8 Click OK.

Also the kappa QW variable will be a real variable.

ADD STUDY

- I In the Home toolbar, click Add Study to open the Add Study window.
- 2 Go to the Add Study window.
- 3 Find the Studies subsection. In the Select Study tree, select Empty Study.
- 4 Find the Physics interfaces in study subsection. In the table, clear the Solve check box for Electromagnetic Waves, Frequency Domain (ewfd).
- 5 Click Add Study in the window toolbar.
- 6 In the Home toolbar, click Add Study to close the Add Study window.

STUDY 2

Steb 1: Stationary

- I In the Study toolbar, click Study Steps and choose Stationary>Stationary.
- 2 In the Settings window for Stationary, locate the Physics and Variables Selection section.
- 3 Select the Modify model configuration for study step check box.
- 4 In the tree, select Component I (compl)>Definitions>Variables I.
- 5 Click O Disable, to avoid that the previously defined kappa_QW variable will be used in this study.

- 6 In the tree, select Component I (compl)>Electromagnetic Waves, Frequency Domain (ewfd).
- 7 Click O Disable in Model.

Solution 2 (sol2)

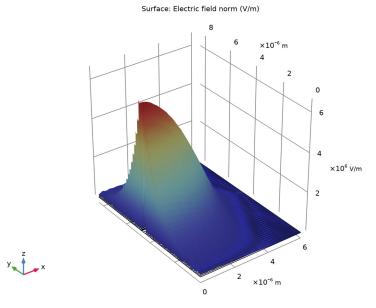
- I In the **Study** toolbar, click **Show Default Solver**, to be able to edit the solver sequence.
- 2 In the Model Builder window, expand the Solution 2 (sol2) node, then click Compile Equations: Stationary.
- 3 In the Settings window for Compile Equations, locate the Study and Step section.
- 4 Select the Split complex variables in real and imaginary parts check box. This will make sure that the real variables defined in the Global Equations will be treated correctly when solving.
- 5 In the Study toolbar, click **Compute**.

RESULTS

Height Expression I

- I In the Model Builder window, expand the Results>Electric Field (ewfd2) node.
- 2 Right-click Surface I and choose Height Expression.

3 Click the Show Legends button in the Graphics toolbar.



Using the **Height Expression** makes the mode field distribution clearer.

Gain Evaluation (ewfd2)

- I In the Results toolbar, click (8.5) Global Evaluation.
- 2 In the Settings window for Global Evaluation, type Gain Evaluation (ewfd2) in the Label text field.
- 3 Locate the Data section. From the Dataset list, choose Study 2/Solution 2 (sol2).
- **4** Locate the **Expressions** section. In the table, enter the following settings:

Expression	Unit	Description
freq1	THz	Frequency
c_const/freq1	nm	Wavelength
kappa_QW	1	Refractive index, QW, imaginary part
-2*kappa_QW*k0	1/cm	Threshold material gain

5 Click **= Evaluate**.

The wavelength and the threshold material gain values agree well with the results in Figs. 2 and 3 of Ref. 1 for oxide position 3.

GLOBAL DEFINITIONS

This part details the step by step instruction to calculate the far-field radiation.

Geometry Parameters

- I In the Model Builder window, under Global Definitions click Geometry Parameters.
- 2 In the Settings window for Parameters, locate the Parameters section.
- **3** In the table, enter the following settings:

Name	Expression	Value	Description
t_GaAs_substrate	1500[nm]	1.5E-6 m	GaAs substrate

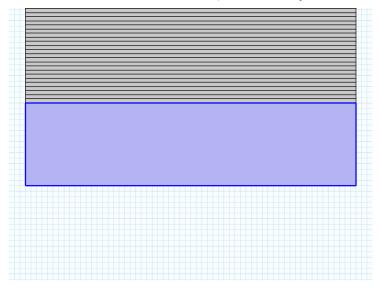
GaAs substrate thickness should be larger than the wavelength.

GEOMETRY I

GaAs Substrate

- I In the Geometry toolbar, click Rectangle.
- 2 In the Settings window for Rectangle, type GaAs Substrate in the Label text field.
- 3 Locate the Size and Shape section. In the Width text field, type d_outer/2.
- 4 In the **Height** text field, type t_GaAs_substrate.
- **5** Locate the **Position** section. In the **z** text field, type -t GaAs substrate.

6 Locate the Selections of Resulting Entities section. Find the Cumulative selection subsection. From the Contribute to list, choose GaAs Layers.



Circle I (c1)

- I In the Geometry toolbar, click Circle.
- 2 In the Settings window for Circle, locate the Size and Shape section.
- 3 In the Radius text field, type d_outer.
- 4 In the Sector angle text field, type 180.
- 5 Locate the Position section. In the z text field, type t_bottom_DBR+t_GaAs_cavity+ t_QW/2.
- 6 Locate the Rotation Angle section. In the Rotation text field, type -90.
- 7 Click **Build All Objects**.
- 8 Click the **Zoom Extents** button in the **Graphics** toolbar.

MATERIALS

Air domain

- I In the Model Builder window, under Component I (comp I) right-click Materials and choose Blank Material.
- 2 In the Settings window for Material, type Air domain in the Label text field.
- **3** Select Domain 1 only.

4 Locate the **Material Contents** section. In the table, enter the following settings:

Property	Variable	Value	Unit	Property group
Refractive index, real	n_iso ; nii = n_iso,	n_air	1	Refractive index
part	nij = 0			

ADD PHYSICS

- I In the Home toolbar, click Add Physics to open the Add Physics window.
- 2 Go to the Add Physics window.
- 3 In the tree, select Optics>Wave Optics>Electromagnetic Waves, Frequency Domain (ewfd).
- 4 Click Add to Component I in the window toolbar.

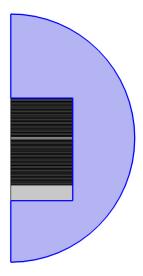
ELECTROMAGNETIC WAVES, FREQUENCY DOMAIN 3 (EWFD3)

- I In the Settings window for Electromagnetic Waves, Frequency Domain, locate the Out-of-Plane Wave Number section.
- 2 In the m text field, type 1.

Far-Field Domain 1

- I Right-click Component I (comp1)>Electromagnetic Waves, Frequency Domain 3 (ewfd3) and choose Far-Field Domain.
- 2 In the Settings window for Far-Field Domain, locate the Domain Selection section.
- 3 Click Clear Selection.

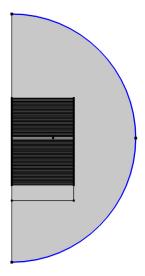
4 Select Domain 1 only.



Far-Field Calculation I

- I In the Model Builder window, expand the Far-Field Domain I node, then click Far-Field Calculation 1.
- 2 In the Settings window for Far-Field Calculation, locate the Boundary Selection section.
- 3 Click Clear Selection.
- 4 Click Paste Selection.
- 5 In the Paste Selection dialog box, type 356,357 in the Selection text field.

6 Click OK.



Scattering Boundary Condition I

- I In the Physics toolbar, click Boundaries and choose Scattering Boundary Condition.
- **2** Select Boundaries 356 and 357 only. The scattering boundaries are same as the far-field boundaries.

MESH I

Size 7

- I In the Model Builder window, under Component I (compl) right-click Mesh I and choose Size.
- 2 In the Settings window for Size, locate the Geometric Entity Selection section.
- 3 From the Geometric entity level list, choose Domain.
- 4 Select Domain 1 only.
- **5** Locate the **Element Size** section. Click the **Custom** button.
- 6 Locate the Element Size Parameters section.
- 7 Select the Maximum element size check box. In the associated text field, type 1da0/6.
- 8 Right-click Size 7 and choose Move Up.
- 9 Click III Build All.

ADD STUDY

- I In the Home toolbar, click Add Study to open the Add Study window.
- 2 Go to the Add Study window.
- 3 Find the Studies subsection. In the Select Study tree, select General Studies> Eigenfrequency.
- 4 Right-click and choose Add Study.

STUDY 3

Step 1: Eigenfrequency

- I In the Model Builder window, under Study 3 click Step 1: Eigenfrequency.
- 2 In the Settings window for Eigenfrequency, locate the Study Settings section.
- 3 Select the **Desired number of eigenfrequencies** check box. In the associated text field, type 1.
- 4 In the Search for eigenfrequencies around shift text field, type f0.
- 5 Locate the Physics and Variables Selection section. Select the Modify model configuration for study step check box.
- 6 In the tree, select Component I (compl)>Electromagnetic Waves, Frequency Domain (ewfd).
- 7 Click Disable in Model.
- 8 In the tree, select Component I (compl)>Electromagnetic Waves, Frequency Domain 2 (ewfd2).
- 9 Click / Disable in Model.
- **10** In the **Home** toolbar, click **Compute**.

RESULTS

Eigenfrequencies (ewfd3)

- I In the Model Builder window, expand the Results>Derived Values node, then click Eigenfrequencies (ewfd3).
- 2 In the Settings window for Global Evaluation, locate the Expressions section.
- **3** In the table, enter the following settings:

Expression	Unit	Description
ewfd3.lambda0	nm	Wavelength in free space

4 Click **= Evaluate**.

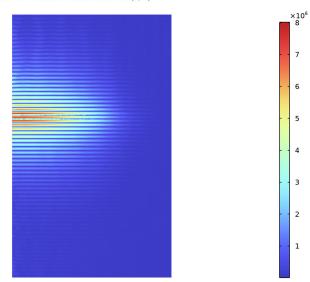
Electric Field (ewfd3)

- I In the Model Builder window, expand the Results>Electric Field (ewfd3) node, then click Electric Field (ewfd3).
- 2 In the Settings window for 2D Plot Group, locate the Plot Settings section.
- 3 Clear the Plot dataset edges check box.

Selection 1

- I In the Model Builder window, right-click Surface I and choose Selection.
- 2 In the Settings window for Selection, locate the Selection section.
- 3 Click Paste Selection.
- 4 In the Paste Selection dialog box, type 2-118 in the Selection text field.
- 5 Click OK.
- 6 In the Electric Field (ewfd3) toolbar, click Plot.
- 7 Click the **Toom Extents** button in the **Graphics** toolbar.

Eigenfrequency=305.81 THz Surface: Electric field norm (V/m)



The mode is centered between the top and bottom DBRs, and is consistent with the case when Impedance Boundary Condition is used.

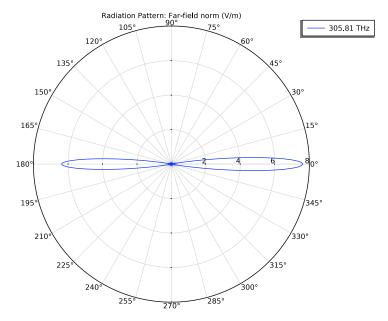
2D Far Field (ewfd3)

I In the Model Builder window, under Results click 2D Far Field (ewfd3).

- 2 In the Settings window for Polar Plot Group, locate the Data section.
- 3 From the Eigenfrequency selection list, choose First.

Radiation Pattern 1

- I In the Model Builder window, expand the 2D Far Field (ewfd3) node, then click Radiation Pattern I.
- 2 In the Settings window for Radiation Pattern, locate the Evaluation section.
- 3 Find the Angles subsection. In the Number of angles text field, type 540. This improves the resolution and smoothness of the plot.
- 4 In the 2D Far Field (ewfd3) toolbar, click Plot.



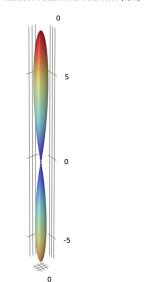
Radiation Pattern I

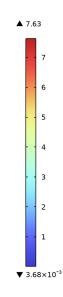
- I In the Model Builder window, expand the Results>3D Far Field (ewfd3) node, then click Radiation Pattern I.
- 2 In the Settings window for Radiation Pattern, locate the Evaluation section.
- 3 Find the Angles subsection. In the Number of elevation angles text field, type 540.

4 In the 3D Far Field (ewfd3) toolbar, click Plot.

Eigenfrequency=305.81 THz

Radiation Pattern: Far-field norm (V/m)





ADD PHYSICS

- I Go to the Add Physics window.
- 2 In the tree, select Optics>Wave Optics>Electromagnetic Waves, Frequency Domain (ewfd).
- **3** Click **Add to Component I** in the window toolbar.

ELECTROMAGNETIC WAVES, FREQUENCY DOMAIN 4 (EWFD4)

- I In the Settings window for Electromagnetic Waves, Frequency Domain, locate the Out-of-Plane Wave Number section.
- 2 In the m text field, type 1.

Initial Values 1

- I In the Model Builder window, under Component I (compl)>Electromagnetic Waves, Frequency Domain 4 (ewfd4) click Initial Values I.
- 2 In the Settings window for Initial Values, locate the Initial Values section.
- **3** Specify the **E**4 vector as

withsol('sol3',ewfd3.Er)	r
--------------------------	---

<pre>withsol('sol3',ewfd3.Er)</pre>	phi
<pre>withsol('sol3',ewfd3.Er)</pre>	z

Frequency

- I In the Physics toolbar, click A Global and choose Global Equations.
- 2 In the Settings window for Global Equations, type Frequency in the Label text field.
- **3** Locate the **Global Equations** section. In the table, enter the following settings:

Name	f(u,ut,utt,t) (1)	Initial value (u_0) (1)	Initial value (u_t0) (1/s)	Description
freq2	<pre>intop1(real(withso l('sol3', ewfd3.Er)))- intop1(real(ewfd4. Er))</pre>	<pre>withsol(' sol3', ewfd3.fre q)</pre>	0	Frequency

- 4 Click to expand the **Discretization** section. From the Value type when using splitting of complex variables list, choose Real.
- 5 Locate the Units section. Click Select Dependent Variable Quantity.
- 6 In the Physical Quantity dialog box, type frequency in the text field.
- 7 Click **Filter**.
- 8 In the tree, select General>Frequency (Hz).
- 9 Click OK.
- 10 In the Settings window for Global Equations, locate the Units section.
- II Click Select Source Term Quantity.
- 12 In the Physical Quantity dialog box, type electric in the text field.
- 13 Click **Filter**.
- 14 In the tree, select Electromagnetics>Electric field (V/m).
- I5 Click OK.

Gain

- I In the Physics toolbar, click A Global and choose Global Equations.
- 2 In the Settings window for Global Equations, type Gain in the Label text field.

3 Locate the Global Equations section. In the table, enter the following settings:

Name	f(u,ut,utt,t) (1)	Initial value (u_0) (1)	Initial value (u_t0) (1/s)	Description
kappa_QW2	<pre>intop1(imag(with sol('sol3', ewfd3.Er)))- intop1(imag(ewfd 4.Er))</pre>	kappa_QW_ gain	0	Refractive index, QW, imaginary part

ADD STUDY

- I Go to the Add Study window.
- 2 Find the Studies subsection. In the Select Study tree, select Empty Study.
- 3 Right-click and choose Add Study.

STUDY 4

Steb 1: Stationary

- I In the Study toolbar, click Study Steps and choose Stationary>Stationary.
- 2 In the Settings window for Stationary, locate the Physics and Variables Selection section.
- 3 Select the Modify model configuration for study step check box.
- 4 In the tree, select Component I (compl)>Electromagnetic Waves, Frequency Domain (ewfd).
- 5 Click Disable in Model.
- 6 In the tree, select Component I (compl)>Electromagnetic Waves, Frequency Domain 2 (ewfd2).
- 7 Click Disable in Model.
- 8 In the tree, select Component I (compl)>Electromagnetic Waves, Frequency Domain 3 (ewfd3).
- 9 Click Disable in Model.
- 10 In the Study toolbar, click **Compute**.

RESULTS

Electric Field (ewfd4)

- I In the Home toolbar, click Add Plot Group and choose 2D Plot Group.
- 2 In the Settings window for 2D Plot Group, type Electric Field (ewfd4) in the Label text field.

- 3 Locate the Data section. From the Dataset list, choose Study 4/Solution 4 (sol4).
- 4 Locate the Plot Settings section. Clear the Plot dataset edges check box.
- 5 Locate the Color Legend section. Clear the Show legends check box.

Surface I

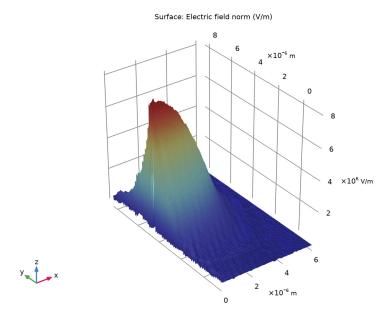
Right-click Electric Field (ewfd4) and choose Surface.

Selection 1

- I In the Model Builder window, right-click Surface I and choose Selection.
- 2 In the Settings window for Selection, locate the Selection section.
- 3 Click Paste Selection.
- 4 In the Paste Selection dialog box, type 2-136 in the Selection text field.
- 5 Click OK.

Height Expression I

In the Model Builder window, right-click Surface I and choose Height Expression.



Gain Evaluation (ewfd4)

- I In the Results toolbar, click (8.5) Global Evaluation.
- 2 In the Settings window for Global Evaluation, type Gain Evaluation (ewfd4) in the Label text field.

- 3 Locate the Data section. From the Dataset list, choose Study 4/Solution 4 (sol4).
- **4** Locate the **Expressions** section. In the table, enter the following settings:

Expression	Unit	Description	
freq2	THz	Frequency	
c_const/freq2	nm	Wavelength	
kappa_QW2	1	Refractive index, QW, imaginary part	
-2*kappa_QW2*k0	1/cm	Threshold material gain	

5 Click **= Evaluate**.

Appendix: Geometry Modeling Instructions

The following instructions will build the VCSEL geometry and define some useful selections.

From the File menu, choose New.

NEW

In the New window, click Model Wizard.

MODEL WIZARD

- I In the Model Wizard window, click 2D Axisymmetric.
- 2 Click M Done.

GLOBAL DEFINITIONS

Geometry Parameters

Start by adding some parameters defining the geometry.

- I In the Model Builder window, under Global Definitions click Parameters I.
- 2 In the Settings window for Parameters, type Geometry Parameters in the Label text field.
- 3 Locate the Parameters section. Click **Load from File**.
- 4 Browse to the model's Application Libraries folder and double-click the file vertical_cavity_surface_emitting_laser_geometry_parameters.txt.

DBR PAIR

Add a part representing a pair of high- and low-index layers. This part will be used when building the mirror stacks for the laser.

- I In the Model Builder window, right-click Global Definitions and choose Geometry Parts> 2D Part
- 2 In the Settings window for Part, type DBR Pair in the Label text field.
- 3 Locate the Input Parameters section. Click Load from File.
- **4** Browse to the model's Application Libraries folder and double-click the file vertical_cavity_surface_emitting_laser_dbr_pair_parameters.txt.

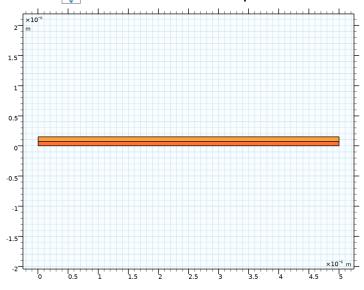
Bottom Layer

- I In the **Geometry** toolbar, click Rectangle.
- 2 In the Settings window for Rectangle, type Bottom Layer in the Label text field.
- 3 Locate the Size and Shape section. In the Width text field, type w.
- 4 In the **Height** text field, type d1.
- **5** Locate the **Position** section. In the **x** text field, type **pos x**.
- 6 In the y text field, type pos y.
- 7 Locate the Selections of Resulting Entities section. Select the Resulting objects selection check box.
- 8 From the Color list, choose Color 8.

Tob Layer

- I Right-click Bottom Layer and choose Duplicate.
- 2 In the Settings window for Rectangle, type Top Layer in the Label text field.
- 3 Locate the Size and Shape section. In the Height text field, type d2.
- **4** Locate the **Position** section. In the **y** text field, type pos_y+d1.
- 5 Locate the Selections of Resulting Entities section. From the Color list, choose Color 18.
- 6 In the Geometry toolbar, click **Build All**.

7 Click the **Zoom Extents** button in the **Graphics** toolbar.



GEOMETRY I

Now, use the part to start building the bottom mirror.

DBR Pair I (pil)

- I In the Geometry toolbar, click Part Instance and choose DBR Pair.
- 2 In the Settings window for Part Instance, locate the Input Parameters section.
- **3** In the table, enter the following settings:

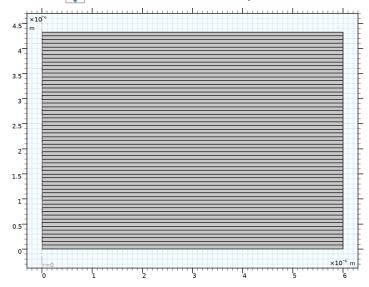
Name	Expression	Value	Description
dl	t_AlGaAs_DBR	7.963E-8 m	Thickness, bottom layer
d2	t_GaAs_DBR	6.949E-8 m	Thickness, top layer
w	d_outer/2	6E-6 m	Width

- **4** Click to expand the **Domain Selections** section. Click to select row number 1 in the table.
- 5 Click New Cumulative Selection.
- 6 In the New Cumulative Selection dialog box, type AlGaAs Layers in the Name text field. The cumulative selections will later be used when assigning the materials and when building the mesh sequence.
- 7 Click OK.
- 8 In the Settings window for Part Instance, locate the Domain Selections section.

- **9** Click to select row number 2 in the table.
- 10 Click New Cumulative Selection.
- II In the New Cumulative Selection dialog box, type GaAs Layers in the Name text field.
- I2 Click OK.

Bottom DBR

- I In the Geometry toolbar, click Transforms and choose Array.
- 2 In the Settings window for Array, type Bottom DBR in the Label text field.
- 3 Click in the **Graphics** window and then press Ctrl+A to select both objects.
- 4 Locate the Size section. From the Array type list, choose Linear.
- 5 In the Size text field, type N_bottom_DBR.
- 6 Locate the **Displacement** section. In the z text field, type t DBR pair.
- 7 Click Build All Objects.
- 8 Click the **Zoom Extents** button in the **Graphics** toolbar.

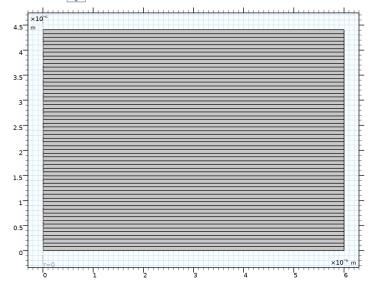


In the following instructions, you will see many Build All Objects instructions followed by a Zoom Extents instructions. Performing those steps will help you display your progress, when building the VCSEL geometry. However, they are not necessary for building a correct geometry.

Top Layer in Bottom DBR

I In the **Geometry** toolbar, click

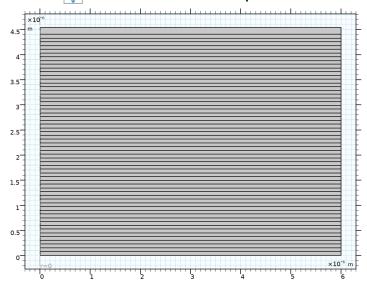
- 2 In the Settings window for Rectangle, type Top Layer in Bottom DBR in the Label text field.
- 3 Locate the Size and Shape section. In the Width text field, type d outer/2.
- 4 In the **Height** text field, type t_AlGaAs_DBR.
- **5** Locate the **Position** section. In the **z** text field, type N_bottom_DBR*t_DBR_pair.
- 6 Locate the Selections of Resulting Entities section. Find the Cumulative selection subsection. From the Contribute to list, choose AlGaAs Layers.
- 7 Click **Build All Objects**.
- 8 Click the **Zoom Extents** button in the **Graphics** toolbar.



Bottom GaAs Layer in Lambda Cavity

- I Right-click Top Layer in Bottom DBR and choose Duplicate.
- 2 In the Settings window for Rectangle, type Bottom GaAs Layer in Lambda Cavity in the Label text field.
- 3 Locate the Size and Shape section. In the Height text field, type t GaAs cavity.
- **4** Locate the **Position** section. In the **z** text field, type t_bottom_DBR.
- 5 Locate the Selections of Resulting Entities section. Find the Cumulative selection subsection. From the Contribute to list, choose GaAs Layers.
- 6 Click **Build All Objects**.

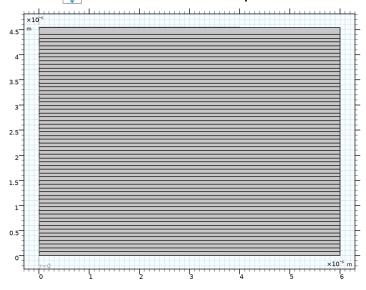
7 Click the ++ Zoom Extents button in the Graphics toolbar.



QW Gain Domain in Lambda Cavity

- I Right-click Bottom GaAs Layer in Lambda Cavity and choose Duplicate.
- 2 In the Settings window for Rectangle, type QW Gain Domain in Lambda Cavity in the Label text field.
- 3 Locate the Size and Shape section. In the Width text field, type d_oxide/2.
- 4 In the Height text field, type t QW.
- 5 Locate the Position section. In the z text field, type t_bottom_DBR+t_GaAs_cavity.
- 6 Locate the Selections of Resulting Entities section. Find the Cumulative selection subsection. Click New.
- 7 In the New Cumulative Selection dialog box, type QW Gain Domain in the Name text field.
- 8 Click OK.
- 9 In the Settings window for Rectangle, click **Build All Objects**.

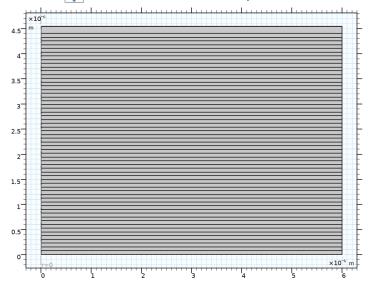
10 Click the ★+▶ Zoom Extents button in the Graphics toolbar.



QW Loss Domain in Lambda Cavity

- I Right-click QW Gain Domain in Lambda Cavity and choose Duplicate.
- 2 In the Settings window for Rectangle, type QW Loss Domain in Lambda Cavity in the Label text field.
- 3 Locate the Size and Shape section. In the Width text field, type (d_outer-d_oxide)/2.
- 4 Locate the **Position** section. In the r text field, type d oxide/2.
- 5 Locate the Selections of Resulting Entities section. Find the Cumulative selection subsection. Click New.
- 6 In the New Cumulative Selection dialog box, type QW Loss Domain in the Name text field.
- 7 Click OK.
- 8 In the Settings window for Rectangle, click **Build All Objects**.

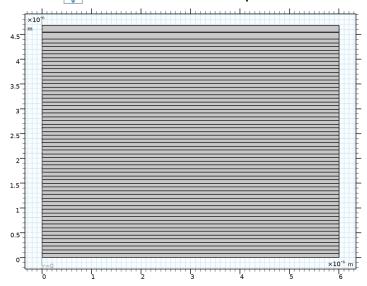
9 Click the Zoom Extents button in the Graphics toolbar.



Top GaAs Layer in Lambda Cavity

- I In the Model Builder window, under Component I (compl)>Geometry I right-click Bottom GaAs Layer in Lambda Cavity (r2) and choose Duplicate.
- 2 In the Settings window for Rectangle, type Top GaAs Layer in Lambda Cavity in the Label text field.
- **3** Locate the **Position** section. In the **z** text field, type t_bottom_DBR+t_GaAs_cavity+ t_QW.
- 4 Click Build All Objects.

5 Click the ++ Zoom Extents button in the Graphics toolbar.



A layer with zero thickness cannot be added to the geometry sequence. Thus, enclose this layer within an if statement.

If Bottom AlGaAs Layer in Oxide Window is Finite

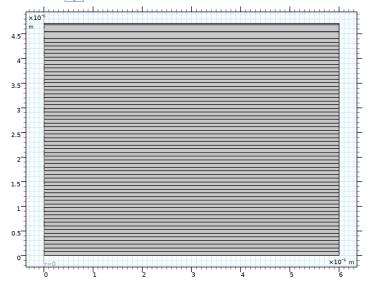
- I In the Geometry toolbar, click Programming and choose If + End If.
- 2 In the Settings window for If, type If Bottom AlGaAs Layer in Oxide Window is Finite in the Label text field.
- 3 Locate the If section. In the Condition text field, type t_AlGaAs_oxide_window_bottom_layer>0.

Bottom AlGaAs Layer in Oxide Window

- I In the Model Builder window, under Component I (compl)>Geometry I right-click Top Layer in Bottom DBR (rI) and choose Duplicate.
- 2 In the Settings window for Rectangle, type Bottom AlGaAs Layer in Oxide Window in the Label text field.
- 3 Locate the Size and Shape section. In the Height text field, type t_AlGaAs_oxide_window_bottom_layer.
- 4 Locate the **Position** section. In the **z** text field, type t bottom DBR+t cavity.

End If Bottom AlGaAs Layer in Oxide Window is Finite

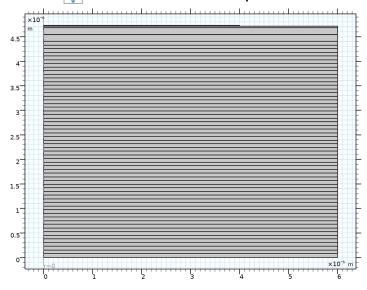
- I In the Model Builder window, under Component I (compl)>Geometry I click End If I (endifl).
- 2 In the Settings window for End If, type End If Bottom AlGaAs Layer in Oxide Window is Finite in the Label text field.
- 3 Click Build All Objects.
- 4 Click the **Zoom Extents** button in the **Graphics** toolbar.



AlAs Domain in Oxide Window

- I In the Model Builder window, under Component I (compl)>Geometry I right-click
 Bottom AlGaAs Layer in Oxide Window (r6) and choose Duplicate.
- 2 Drag and drop Bottom AlGaAs Layer in Oxide Window I (r7) below End If Bottom AlGaAs Layer in Oxide Window is Finite (endif1).
- 3 In the Settings window for Rectangle, type AlAs Domain in Oxide Window in the Label text field.
- 4 Locate the Size and Shape section. In the Width text field, type d_oxide/2.
- 5 In the Height text field, type t oxide.
- 6 Locate the Position section. In the z text field, type t_bottom_DBR+t_cavity+ t_AlGaAs_oxide_window_bottom_layer.
- 7 Locate the Selections of Resulting Entities section. Find the Cumulative selection subsection. Click New.

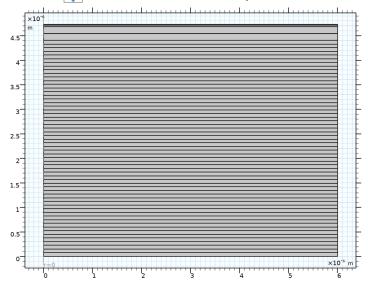
- 8 In the New Cumulative Selection dialog box, type AlAs Domain in the Name text field.
- 9 Click OK.
- 10 In the Settings window for Rectangle, click | Build All Objects.
- II Click the **Zoom Extents** button in the **Graphics** toolbar.



AlOx Domain in Oxide Window

- I Right-click AIAs Domain in Oxide Window and choose Duplicate.
- 2 In the Settings window for Rectangle, type Alox Domain in Oxide Window in the Label text field.
- 3 Locate the Size and Shape section. In the Width text field, type (d_outer-d_oxide)/2.
- 4 Locate the **Position** section. In the r text field, type d oxide/2.
- 5 Locate the Selections of Resulting Entities section. Find the Cumulative selection subsection. Click New.
- 6 In the New Cumulative Selection dialog box, type Alox Domain in the Name text field.
- 7 Click OK.
- 8 In the Settings window for Rectangle, click **Build All Objects**.

9 Click the ++ Zoom Extents button in the Graphics toolbar.



Bottom AlGaAs Layer in Oxide Window (r6), End If Bottom AlGaAs Layer in Oxide Window is Finite (endif1), If Bottom AlGaAs Layer in Oxide Window is Finite (if1)

- I In the Model Builder window, under Component I (compl)>Geometry I, Ctrl-click to select If Bottom AlGaAs Layer in Oxide Window is Finite (if1), Bottom AlGaAs Layer in Oxide Window (r6), and End If Bottom AlGaAs Layer in Oxide Window is Finite (endif1).
- 2 Right-click and choose **Duplicate**.

If Second AlGaAs Layer in Oxide Window is Finite

- I In the Settings window for If, type If Second AlGaAs Layer in Oxide Window is Finite in the Label text field.
- 2 Locate the If section. In the Condition text field, type t_AlGaAs_oxide_window_second_layer>0.

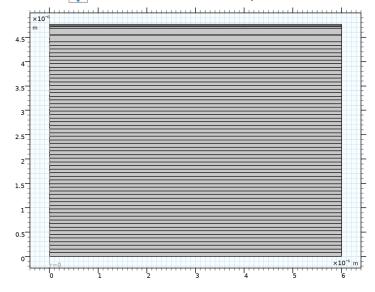
Second AlGaAs Layer in Oxide Window

- I In the Model Builder window, under Component I (compl)>Geometry I click Bottom AlGaAs Layer in Oxide Window I (r9).
- 2 In the Settings window for Rectangle, type Second AlGaAs Layer in Oxide Window in the Label text field.
- 3 Locate the Size and Shape section. In the Height text field, type t AlGaAs oxide window second layer.

4 Locate the Position section. In the z text field, type t bottom DBR+t cavity+ t_AlGaAs_oxide_window_bottom_layer+t_oxide.

End If Second AlGaAs Layer in Oxide Window is Finite

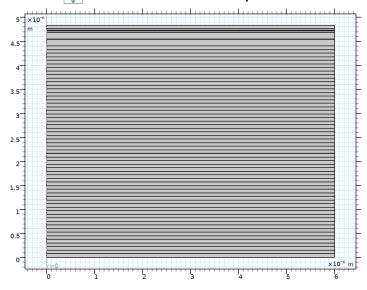
- I In the Model Builder window, under Component I (compl)>Geometry I click End If Bottom AlGaAs Layer in Oxide Window is Finite I (endif2).
- 2 In the Settings window for End If, type End If Second AlGaAs Layer in Oxide Window is Finite in the Label text field.
- 3 Click Build All Objects.
- 4 Click the **Zoom Extents** button in the **Graphics** toolbar.



Top GaAs Layer in Oxide Window

- I In the Model Builder window, under Component I (compl)>Geometry I right-click Bottom GaAs Layer in Lambda Cavity (r2) and choose Duplicate.
- 2 In the Settings window for Rectangle, type Top GaAs Layer in Oxide Window in the Label text field.
- 3 Locate the Size and Shape section. In the Height text field, type t GaAs DBR.
- 4 Locate the Position section. In the z text field, type t bottom DBR+t cavity+ t_AlGaAs_oxide_window_bottom_layer+t_oxide+ t AlGaAs oxide window second layer.
- 5 Click **Build All Objects**.

6 Click the **Zoom Extents** button in the **Graphics** toolbar.



DBR Pair 2 (pi2)

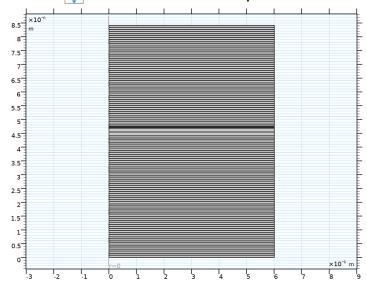
- I In the Model Builder window, under Component I (compl)>Geometry I right-click DBR Pair I (pil) and choose Duplicate.
- 2 In the Settings window for Part Instance, locate the Input Parameters section.
- **3** In the table, enter the following settings:

Name	Expression	Value	Description
pos_y	t_bottom_DBR+ t_cavity+ t_oxide_window	4.8312E-6 m	Vertical position

Top DBR

- In the Geometry toolbar, click Transforms and choose Array.
- 2 In the Settings window for Array, type Top DBR in the Label text field.
- 3 Select the objects pi2(1) and pi2(2) only.
- 4 Locate the Size section. From the Array type list, choose Linear.
- 5 In the Size text field, type N_top_DBR.
- **6** Locate the **Displacement** section. In the **z** text field, type t_DBR_pair.
- 7 Click Build All Objects.

8 Click the **Zoom Extents** button in the **Graphics** toolbar.



This completes the setup of the geometry sequence.